Octal Bus Transceivers (with inverted 3-state outputs)/
Octal Bus Transceivers (with 3-state outputs)

HITACHI

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Description

This octal transceiver is designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timng.

This device allows data transmission from A bus to the B bus or from the B bus to the A bus depending upon the logic levels at the enable inputs (\overline{GBA} and \overline{GAB}).

The enable inputs can be used to disable the device so that the buses are affectively isolated.

The dual-enable configuration gives these devices the capability to store data by simultaneous enabling of $\overline{\text{GBA}}$ and GAB. Each output reinforces its input in this transceiver configuration. Thus, when both control inputs are enabled and all other data sources to the two sets of bus lines are at high impedance, both sets of bus lines (16 in all) will remain at their last states. The 8-bit codes appearing on the two sets of buses will be identical for the HD74HCT623 or complementary for the HD74HCT620.

Features

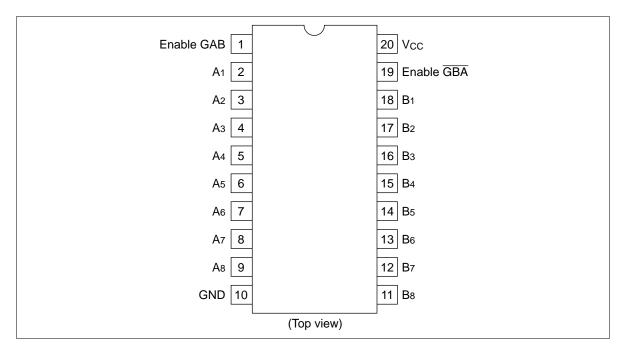
- LSTTL Output Logic Level Compatibility as well as CMOS Output Compatibility
- High Speed Operation: t_{pd} (Bus to Bus) = 15 ns typ ($C_L = 50 \text{ pF}$)
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
- Low Input Current: 1 μA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)



Function Table

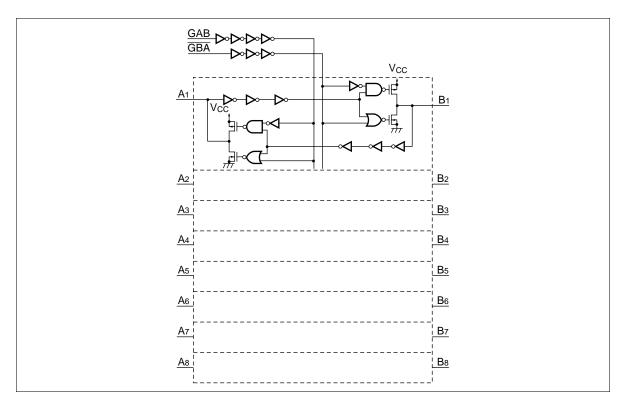
Enable Input		Operation		
GBA	GAB	HD74HCT620	HD74HCT623	_
L	L	B data to A bus	B data to A bus	_
Н	Н	A data to B bus	A data to B bus	
Н	L	Isolation	Isolation	
L	Н	B data to A bus, Ā data to B bus	B data to A bus, A data to B bus	_

Pin Arrangement

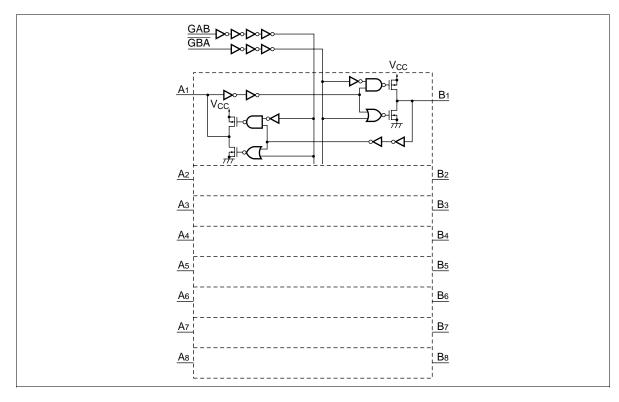


Block Diagram

HD74HCT620



HD74HCT623



Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage range	V _{cc}	-0.5 to +7.0	V
Input voltage	V _{IN}	-0.5 to V_{CC} + 0.5	V
Output voltage	V_{OUT}	-0.5 to $V_{\rm CC}$ + 0.5	V
DC current drain per pin	I _{OUT}	±35	mA
DC current drain per V _{cc} , GND	I _{CC} , I _{GND}	±75	mA
DC input diode current	I _{IK}	±20	mA
DC output diode current	I _{ok}	±20	mA
Power dissipation per package	P _T	500	mW
Storage temperature	Tstg	-65 to +150	°C

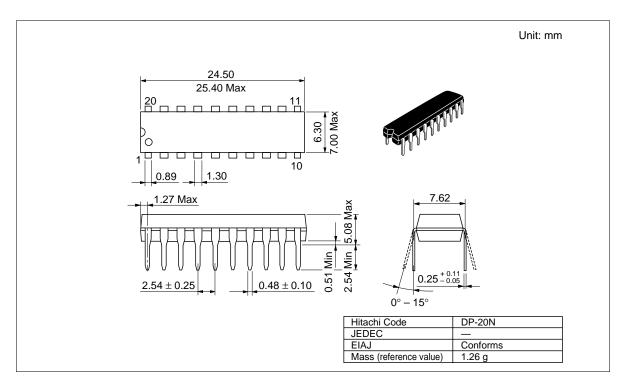
DC Characteristics

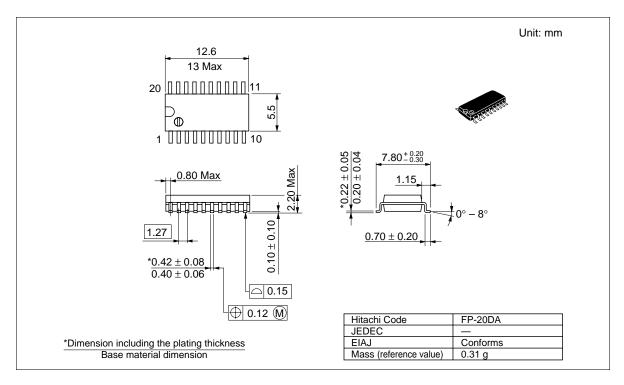
		Ta =	: 25°C	;	Ta = - +85°0	–40 to		Test Co	onditions
Item	Symbol	Min	Тур	Max	Min	Max	Unit	V _{cc} (V)	-
Input voltage	V _{IH}	2.0	_	_	2.0	_	V	4.5 to 5.5	
	V _{IL}	_	_	8.0	_	8.0	V	4.5 to 5.5	
Output voltage	V _{OH}	4.4	_	_	4.4	_	V	4.5	Vin = V_{IH} or V_{IL} I_{OH} = $-20 \mu A$
		4.18	_	_	4.13	_	_	4.5	$I_{OH} = -6 \text{ mA}$
	V _{OL}	_	_	0.1	_	0.1	V	4.5	Vin = V_{IH} or V_{IL} I_{OL} = 20 μ A
		_	_	0.26	_	0.33	_	4.5	$I_{OL} = 6 \text{ mA}$
Off-state output current	l _{oz}	_	_	±0.5	_	±5.0	μΑ	5.5	$Vin = V_{IH} \text{ or } V_{IL},$ $Vout = V_{CC} \text{ or GND}$
Input current	lin	_	_	±0.1	_	±1.0	μΑ	5.5	$Vin = V_{CC}$ or GND
Quiescent supply current	I _{cc}	_	_	4.0	_	40	μА	5.5	Vin = V_{CC} or GND, lout = 0 μ A

AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

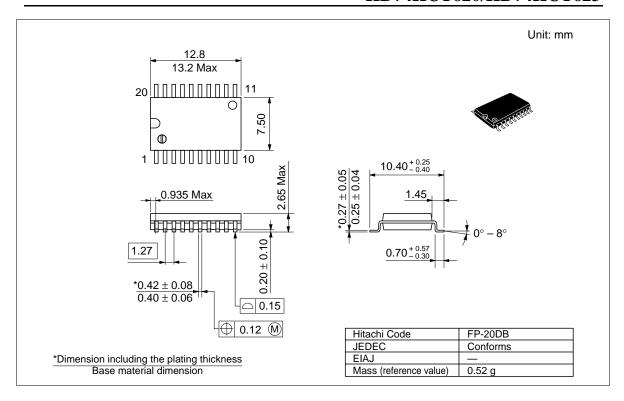
		Ta =	Ta = 25°C		Ta = -40 to +85°C		_	Test Conditions
Item	Symbol	Min	Тур	Max	Min	Max	Unit	V _{cc} (V)
Propagation delay	t _{PLH}	_	13	20	_	25	ns	4.5
time	t _{PHL}	_	16	20	_	25		4.5
Output enable	\mathbf{t}_{ZH}	_	16	30	_	38	ns	4.5
time	t _{zL}	_	16	30	_	38		4.5
Output disable	$t_{\rm HZ}$	_	19	30	_	38	ns	4.5
time	t _{LZ}	_	21	30	_	38		4.5
Output rise/fall time	t _{TLH} t _{THL}	_	4	12	_	15	ns	4.5
Input capacitance	Cin	_	5	10	_	10	pF	_

Package Dimensions





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Hitachi, Ltd.

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica Europe Asia Japan

http://semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg http://sicapac.hitachi-asia.com http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223

Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany

Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road

Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 585160

Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00, Singapore 049318 Tel: <65>-538-6533/538-8577 Fax: <65>-538-6933/538-3877

URL: http://www.hitachi.com.sg Hitachi Asia I td (Taipei Branch Office)

4/F, No. 167, Tun Hwa North Road, Hung-Kuo Building. Taipei (105), Taiwan Tel: <886>-(2)-2718-3666

Fax: <886>-(2)-2718-8180 Telex: 23222 HAS-TP URL: http://www.hitachi.com.tw

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Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon, Hong Kong

Tel: <852>-(2)-735-9218 Fax: <852>-(2)-730-0281 URL: http://www.hitachi.com.hk